

Sodium Metal Anode with Multiphasic Interphase for Room Temperature Sodium-Sulfur Pouch Cells

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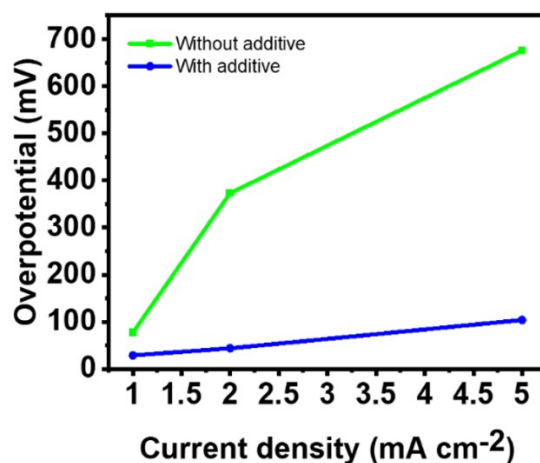


Figure-S1 Sodium symmetric cell (Na//Na) overpotential as a function of current density

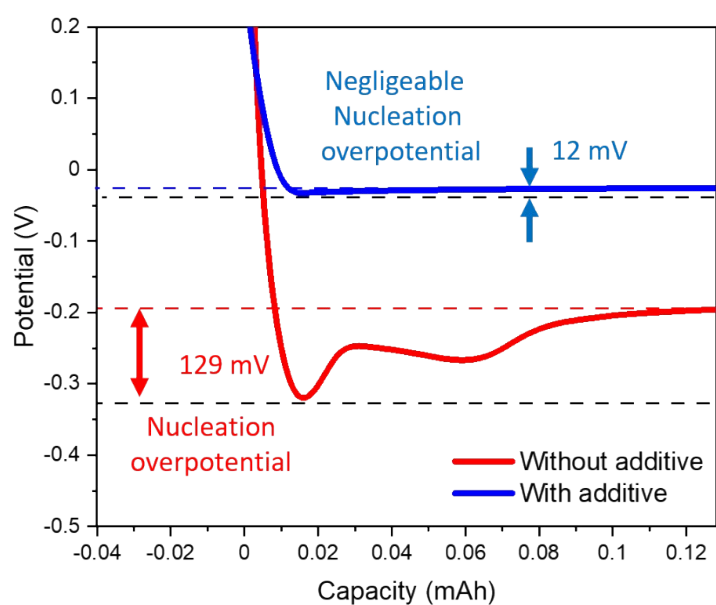


Figure-S2 Nucleation overpotential of Na//Cu half-cell with additive and without additive at 1 mA cm^{-2} current density and 1 mAh cm^{-2} specific capacity.

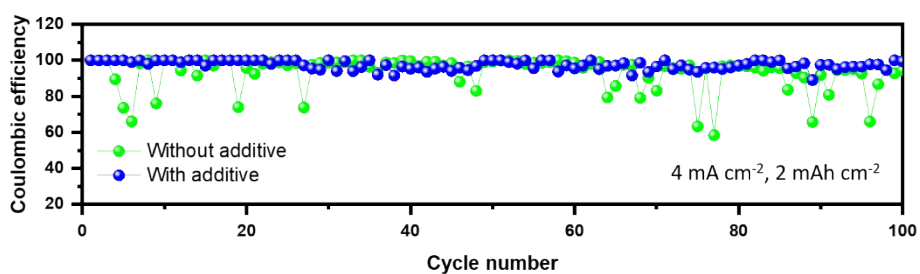


Figure-S3 Coulombic efficiency of Na//Cu half cells at a current density of 4 mA cm^{-2} and capacity of 2 mA h cm^{-2}

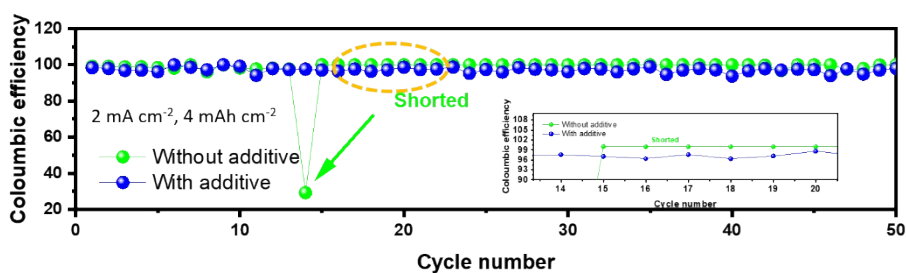


Figure-S4 Coulombic efficiency of Na//Cu half cells at a current density of 2 mA cm^{-2} and capacity of 4 mA h cm^{-2} specific capacity

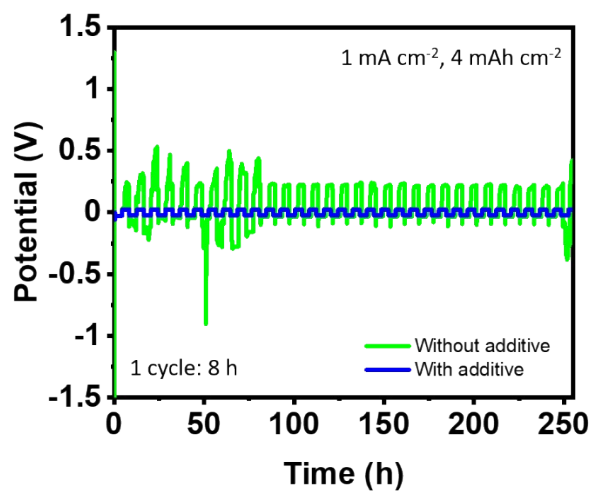


Figure-S5 Na//Na symmetric cell plating/stripping profile with additive and without additive at 1 mA cm^{-2} current density and 4 mA h cm^{-2} specific capacity.

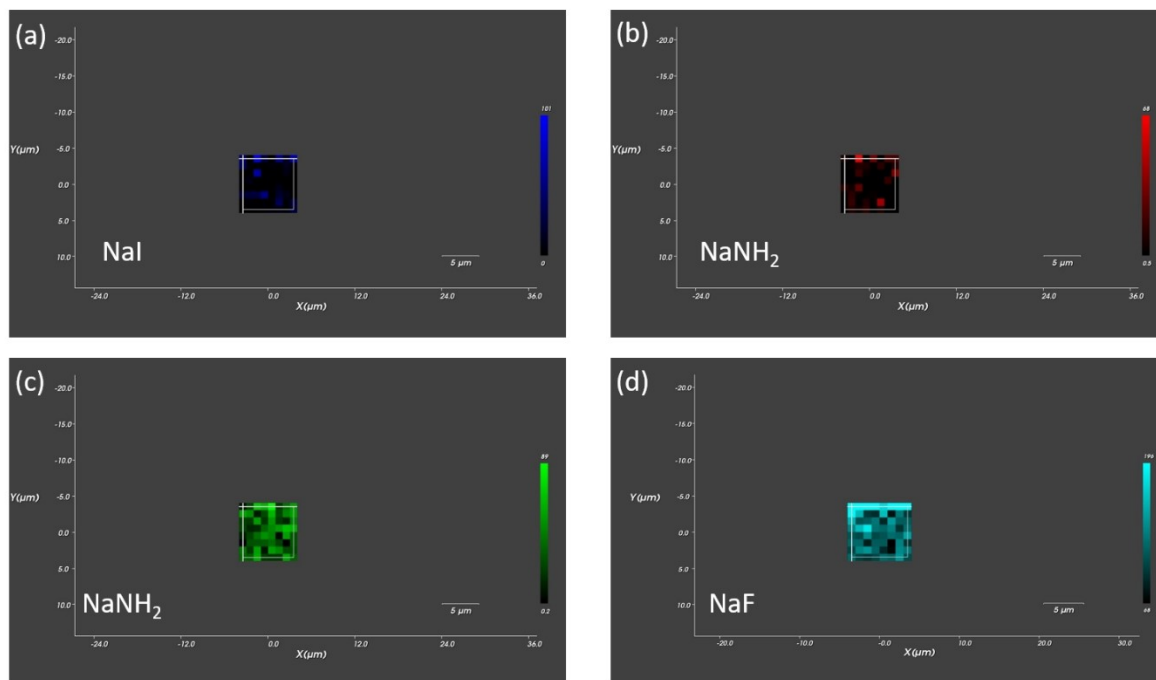


Figure-S6 Raman mapping of different SEI species present on the surface of sodium metal anode after cycling (a) NaI distribution throughout the multiple scans in a region of $5\ \mu\text{m} \times 5\ \mu\text{m}$ around $185\ \text{cm}^{-1}$ Raman shift (b) NaNH_2 distribution throughout the multiple scans in a region of $5\ \mu\text{m} \times 5\ \mu\text{m}$ around $225\ \text{cm}^{-1}$ Raman shift (c) NaNH_2 distribution throughout the multiple scans in a region of $5\ \mu\text{m} \times 5\ \mu\text{m}$ around $344\ \text{cm}^{-1}$ Raman shift (d) NaF distribution throughout the multiple scans in a region of $5\ \mu\text{m} \times 5\ \mu\text{m}$ around $511\ \text{cm}^{-1}$ Raman shift

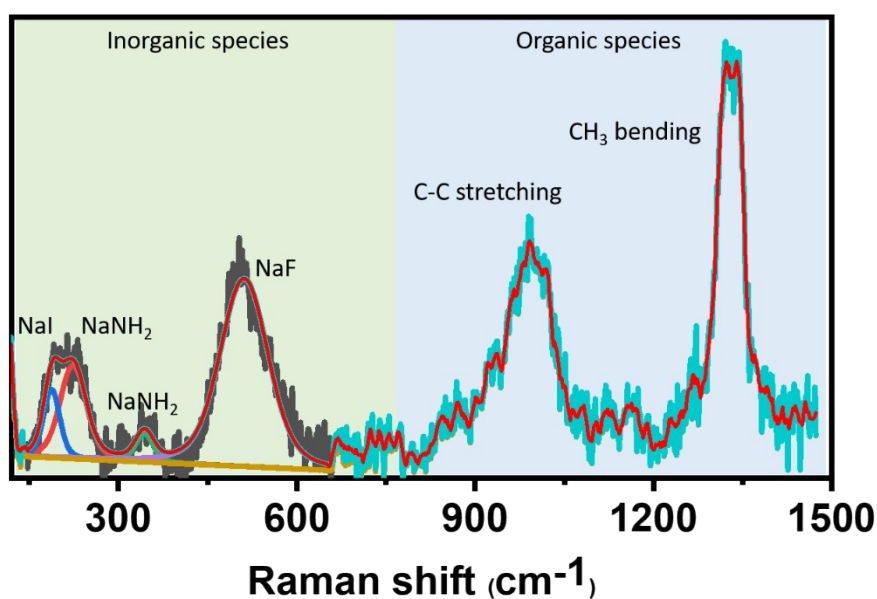


Figure-S7 Raman spectrum of sodium metal anode after 20 plating/stripping cycles in a symmetric cell configuration showing organic and inorganic components in the SEI

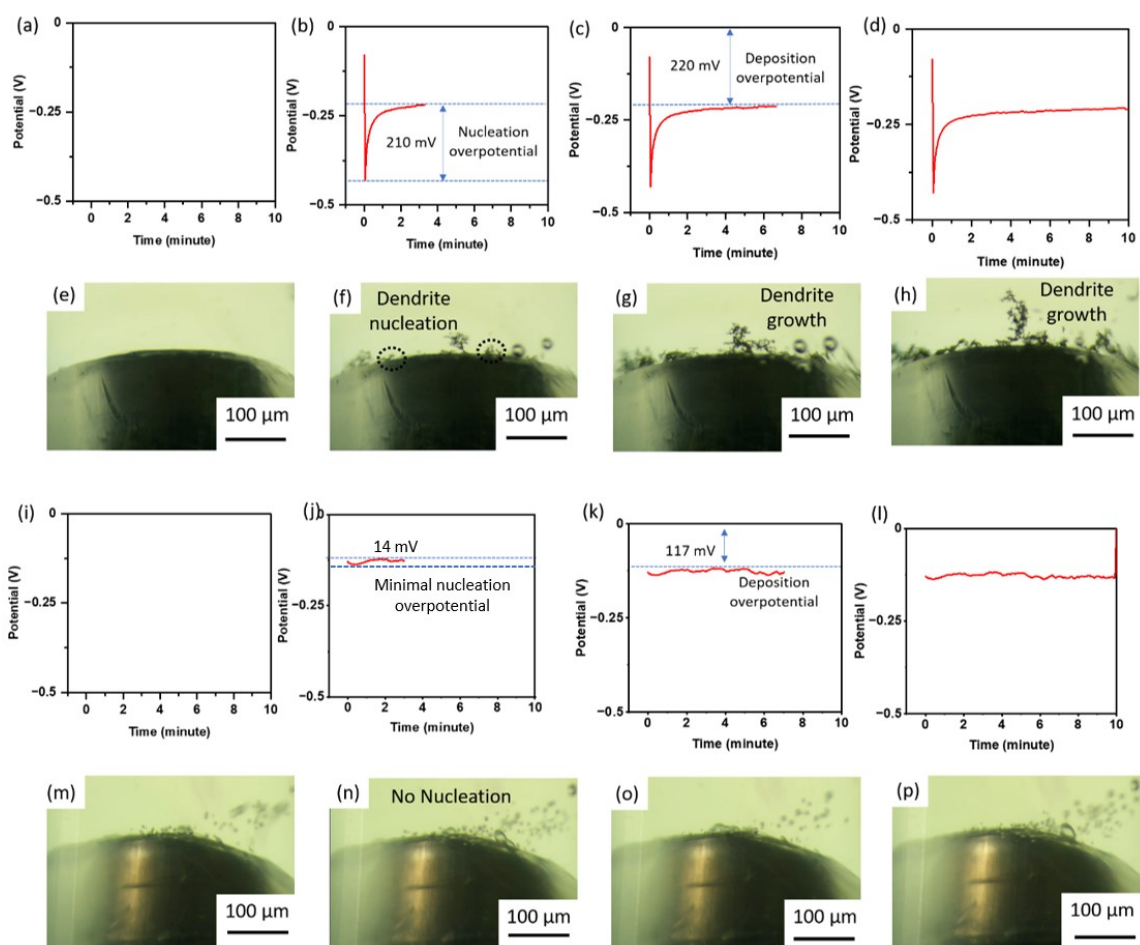


Figure-S8 *In-situ* optical cell testing of sodium metal anode in both the electrolyte systems. (a and e, without additive) at the starting stage of deposition (b and f) after nucleation from 0 to 3 minute of deposition (c and g) nucleation to growth region (d and h) sodium dendrite growth region up to 10 min. (i-m, with additive) at the starting stage of deposition (j and n) after nucleation from 0 to 3 minute of deposition, very less nucleation overpotential (k and o) deposition region (l and p) deposition region up to 10 min.

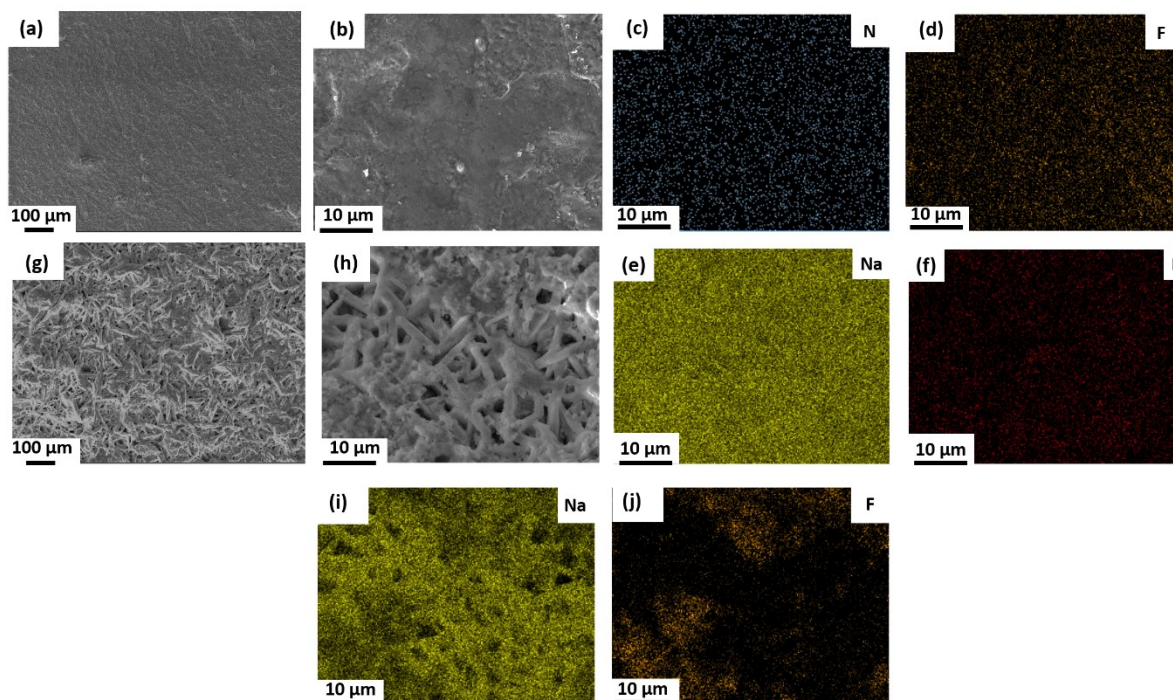


Figure-S9 FESEM images of the sodium surface after 20 plating/stripping cycles in a Na//Na symmetric cell at 1 mA cm^{-2} current density. (a, b) Na surface cycled in MI based electrolyte (c-f) corresponding EDX mapping of sodium anode comprising N, F, Na and I in the deposited layer. (g, h) Na surface in the reference electrolyte cell (i, j) EDX mapping of sodium anode comprising Na and F in the deposited layer.

Table-S1 A fair comparison of Na//Na symmetric cell performance parameters i.e., overpotential and cycle number

Cell type	Salt	Solvent	Additive	Current density (mA cm^{-2})	Capacity (mA h cm^{-2})	Overpotential (mV)	Cycle life (h)
Na//Na (This work)	1 M NaOTf	Diglyme	100 mM Methylammonium iodide	1	1	30-35	>3200
Na//Na ¹	0.8 M NaPF ₆	TMP/FEC	DTD as co-solvent	0.5	1	200	1350

		(7:3)					
Na//Na ²	1 M NaPF ₆	EC/P C	2% TMDT	0.5	1	400	450
Na//Na ³	0.3 M NaPF ₆	EC/P C	Acetamide (BSTFA)	0.5	0.5	120	350
Na//Na ⁴	4 M NaFSI	DMC	1% SbF ₃	0.5	0.5	25	1000
Na//Na ⁵	1 M NaTFSI	FEC	0.75 % NaAsF ₆	0.5	1	500	350
Na//Na ⁶	2 M NaPF ₆	DME/ FEPE	1% SbF ₃	0.5	0.5	200	1200
Na//Na ⁷	1 M NaClO ₄	EC/D EC	0.05 M SnCl ₂	0.5	1	100	500
Na//Na ⁸	1 M NaPF ₆	Digly me	0.033 M Na ₂ S ₆	2	1	38	400
Na//Na ⁹	1 M NaPF ₆	EC/P C	FEC	1	1	100	100
Na//Na ¹⁰	1 M NaOTf	Digly me	100 mM 9-Fluorenone	1	1	30	1200
Na//Na ¹¹	1 M NaPF ₆	EC/P C	1 Wt% Perfluoroben zene	1	1	80	600
Na//Na ¹²	1 M NaPF ₆	Digly me	Cetyltrimethy lammonium bromide	3	3	500	80

Table-S2 Resistance value from EIS data after fitting for both the electrolyte system at different temperature

S. No.	Temperature	Cell	Resistance (R)
1	10 °C (283K)	With additive	103.56
		Without additive	241.82

2	20 °C (293K)	With additive	60.43
		Without additive	134.61
3	30 °C (303K)	With additive	44.30
		Without additive	115.33
4	40 °C (313K)	With additive	29.87
		Without additive	90.47
6	50 °C (323K)	With additive	26.88
		Without additive	61.20
6	60 °C (333K)	With additive	20.14
		Without additive	47.63

Table-S3 XPS peak assignments for organic species in SEI with additive

Element	Peak position	Peak assignment	Species
C	288.2/286.5/284.8	C-O/ /C=O /C-C, C-H	RCH ₂ ONa
	eV		
O	531/535.5	Na-O, C=O/C-O	RCH ₂ ONa, Na ₂ O

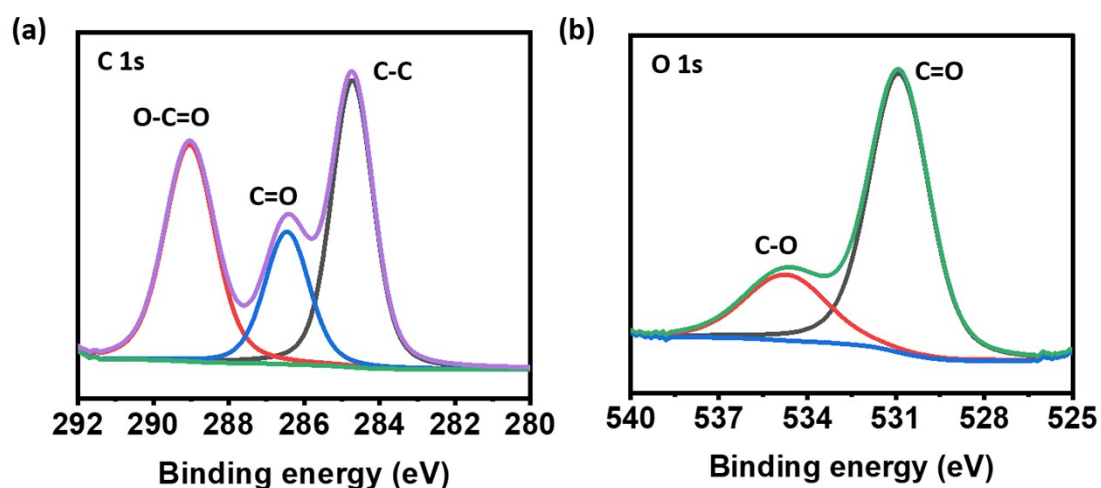


Figure-S10 High-resolution XPS spectra of Na metal anode after 20 plating/stripping cycles at 1 mA cm⁻² current density for (a) C1s and (b) O1s showing organic components in the SEI

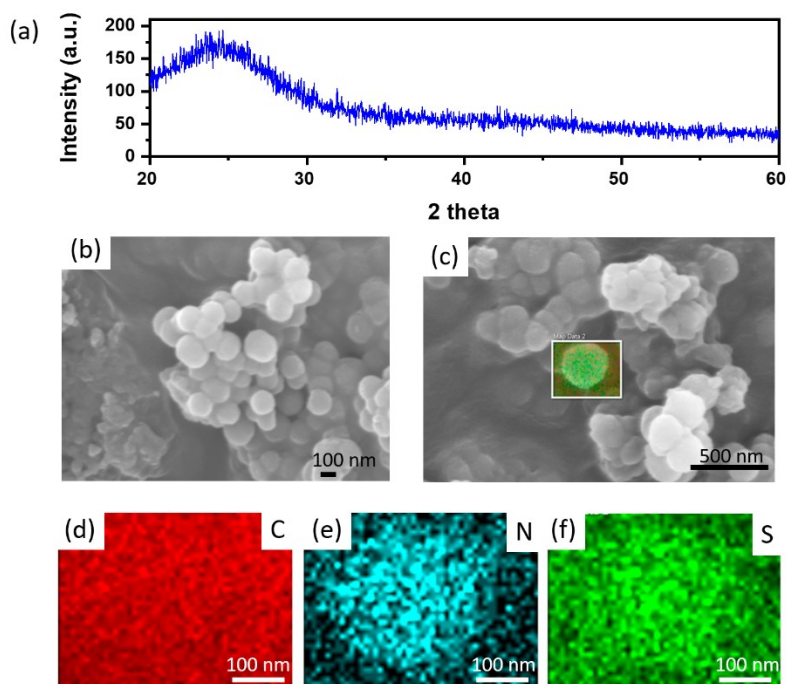


Figure-S11 Microscopic and elemental analysis of the as-synthesized SPAN cathode material (a) showing XRD spectra for said material, all the peaks are corresponding to SPAN (b-c) FESEM images of SPAN powder (d-f) EDX analysis of the said material showing the uniform distribution of N and S in the material

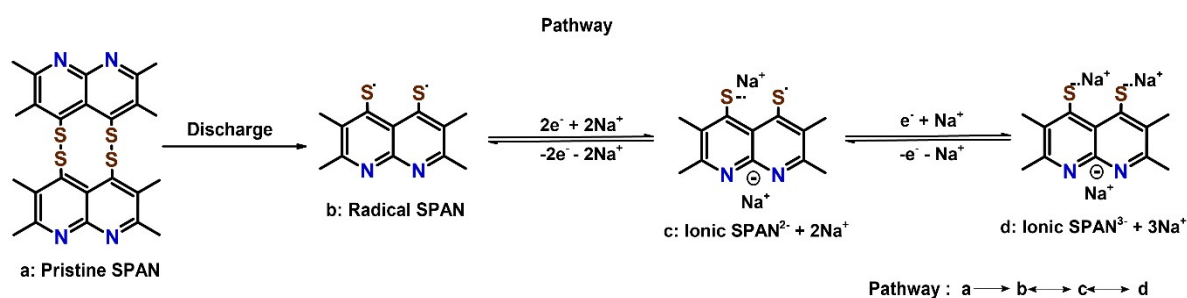


Figure-S12 The possible reaction pathways of SPAN cathode¹³

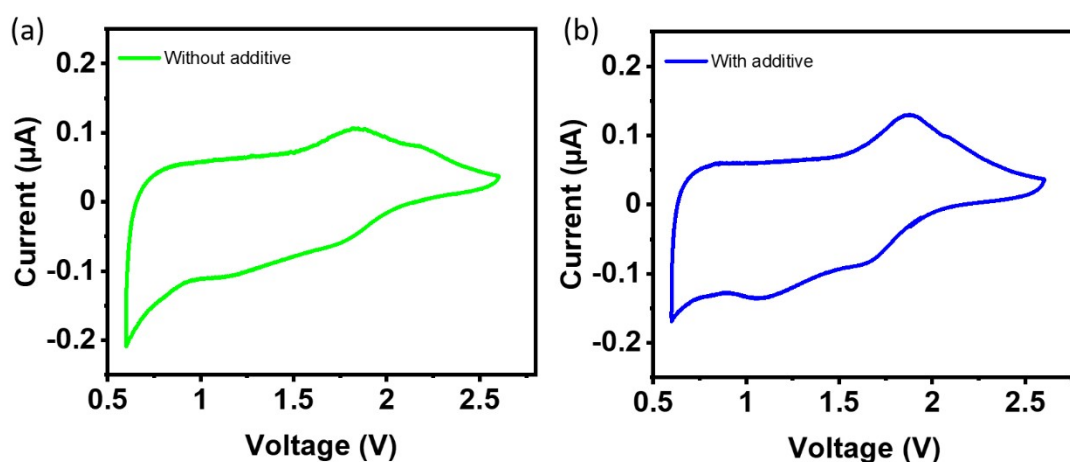


Figure-S13 Cyclic voltammogram for Na//SPAN full cells (a) without and (b) with additive. CVs were conducted at a scan rate of 0.1 mV s^{-1} in a potential window of 0.6 to 2.6 V

References

- 1 M. Zhu, L. Li, Y. Zhang, K. Wu, F. Yu, Z. Huang, G. Wang, J. Li, L. Wen, H. K. Liu, S. X. Dou, Y. Yu and C. Wu, *Energy Storage Mater.*, 2021, **42**, 145–153.
- 2 M. Zhu, Y. Zhang, F. Yu, Z. Huang, Y. Zhang, L. Li, G. Wang, L. Wen, H. K. Liu, S. X. Dou and C. Wu, *Nano Lett.*, 2021, **21**, 619–627.
- 3 R. Jiang, L. Hong, Y. Liu, Y. Wang, S. Patel, X. Feng and H. Xiang, *Energy Storage Mater.*, 2021, **42**, 370–379.
- 4 W. Fang, H. Jiang, Y. Zheng, H. Zheng, X. Liang, Y. Sun, C. Chen and H. Xiang, *J. Power Sources*, 2020, **455**, 227956.
- 5 S. Wang, W. Cai, Z. Sun, F. Huang, Y. Jie, Y. Liu, Y. Chen, B. Peng, R. Cao, G. Zhang and S. Jiao, *Chem. Commun.*, 2019, **55**, 14375–14378.
- 6 W. Fang, R. Jiang, H. Zheng, Y. Zheng, Y. Sun, X. Liang, H. F. Xiang, Y. Z. Feng and Y. Yu, *Rare Met.*, 2021, **40**, 433–439.
- 7 X. Zheng, H. Fu, C. Hu, H. Xu, Y. Huang, J. Wen, H. Sun, W. Luo and Y. Huang, *J. Phys. Chem. Lett.*, 2019, **10**, 707–714.
- 8 H. Wang, C. Wang, E. Matios and W. Li, *Angew. Chemie*, 2018, **130**, 7860–7863.

- 9 M. Han, C. Zhu, T. Ma, Z. Pan, Z. Tao and J. Chen, *Chem. Commun.*, 2018, **54**, 2381–2384.
- 10 C. Bihari, S. Bera, S. K. Vineeth, H. Kumar and V. Kumar, *J. Energy Storage*, 2023, **71**, 108132.
- 11 C. Zhu, D. Wu, Z. Wang, H. Wang, J. Liu, K. Guo, Q. Liu and J. Ma, *Adv. Funct. Mater.*, 2024, **34**, 1–9.
- 12 J. Luo, Y. Zhang, E. Matios, P. Wang, C. Wang, Y. Xu, X. Hu, H. Wang, B. Li and W. Li, *Nano Lett.*, 2022, **22**, 1382–1390.
- 13 C. Sanjaykumar, N. Sungjemmenla, M. Chandra, C. B. Soni, S. K. Vineeth, S. Das, N. Cohen, H. Kumar, D. Mandler and V. Kumar, *J. Mater. Chem. A*, 2024, 1420–1429.